

EE-SX770/771/772/870/871/872(A/P/R)

Thin, Compact Photomicrosensor with Attached Cable

- Next generation design available with NPN or PNP output
- Allows standard M3-screw mounting
- Twenty-four models available in standard, L-shaped, and T-shaped
- UL, EMC and CE approvals
- Each model equipped with a flexible cable that conforms to machine contours
- Compact size allows high-density mounting
- Indicators are visible from both sides
- Readily-visible, molded workpiece insertion mark allows fine-tuning of sensing position



3) *UR***² ***UR*²

Ordering Information _____

Appearance	Sensing method	Sensing distance	Output configuration		Part number (See Note.)
Standard	Through-beam (slot)	5 mm (0.2 in) (slot width)	NPN	Dark-ON	EE-SX770(A)
		1	PNP		EE-SX770(P/R)
		1	NPN	Light-ON	EE-SX870(A)
ii			PNP		EE-SX870(P/R)
L-shaped		1	NPN	Dark-ON	EE-SX771(A)
			PNP		EE-SX771(P/R)
		1	NPN	Light-ON	EE-SX871(A)
11		1	PNP		EE-SX871(P/R)

Note: The operation indicator of models with suffix code (A) or (R) will turn ON when the light is interrupted.

(This table continues on the next page.)

Specifications Table - continued from previous page

Sensing method	Sensing distance	Output configuration		Part number (See Note.)
Through-beam (slot)	5 mm (0.2 in) (slot width)	NPN	Dark-ON	EE-SX772(A)
	1	PNP	1	EE-SX772(P/R)
	1	NPN	Light-ON	EE-SX872(A)
	1	PNP	-	EE-SX872(P/R)
	- u	Through-beam (slot) 5 mm (0.2 in)	Through-beam (slot) 5 mm (0.2 in) (slot width) PNP NPN	Through-beam (slot) 5 mm (0.2 in) (slot width) PNP NPN Light-ON

Note: The operation indicator of models with suffix code (A) or (R) will turn ON when the light is interrupted.

Specifications _____

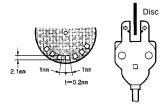
Item		Through-beam models(slot)									
Output configuration Dark-ON Ligh					Light-ON						
Output	Output NPN PNP			NPN PNP							
Model		EE-SX770 EE-SX771 EE-SX772	EE-SX770A EE-SX771A EE-SX772A	EE-SX770P EE-SX771P EE-SX772P	EE-SX770R EE-SX771R EE-SX772R	EE-SX871	EE-SX870A EE-SX871A EE-SX872A		EE-SX870R EE-SX871R EE-SX872R		
Supply voltage	е	5 to 24 VD0	C ± 10%, ripple	(p-p): 10% ma	ax						
Current consumption	NPN models	35 mA max. 30 mA max.									
	PNP models										
Slot width 5 mm			nm								
Standard targe	et object	Opaque: 2 x 0.8 mm min									
Differential travel 0.025 mm											
Control output		NPN open collector output models: At 5 to 24 VDC: 100 mA load current (I _c) with a residual voltage of 0.8 V max. When driving TTL: 40 mA load current (I _c) with a residual voltage of 0.4 V max. PNP open collector output models: At 5 to 24 VDC: 50 mA load current (I _c) with a residual voltage of 1.3 V max.									

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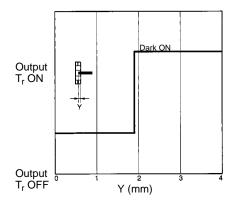
Specifications Table - continued from previous page

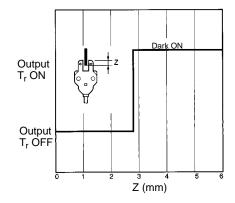
Item		Through-beam models(slot)								
Output confi	guration	Dark-ON				Light-ON				
Output NPN PNP				NPN PNP						
Model EE-SX770 EE-SX770A EE-SX770P EE-SX770R EE-SX870A EE-SX870A EE-SX771 EE-SX771A EE-SX771P EE-SX771R EE-SX871 EE-SX871A EE-SX772 EE-SX772A EE-SX772P EE-SX772R EE-SX872 EE-SX872A						EE-SX870P EE-SX871P EE-SX872P	EE-SX870R EE-SX871R EE-SX872R			
Operation in (See Note 1.		Red LED is	Red LED is ON when the object to be detected is not present							
Response from (See Note 2.		1 kHz								
Light source		GaAs infrare	ed LED with a	peak light wav	elength of 940	nm				
Protective circuit (See Note 3.) Overcurrent protection (built-in circuit)										
Ambient illur	minance	Sensing sur	face: 1,000 ℓx	max with fluor	escent light					
Ambient	Operating	-25°C to 55°	25°C to 55°C (-13°F to 131°F)							
temperature	Storage	-30°C to 80°	-30°C to 80°C (-22°F to 176°F)							
Ambient	Operating	5% to 85%								
humidity	Storage	5% to 95%								
Vibration resistance Destruction: 20 to 2,000 Hz, 1.5-mm double amplitude for 2 hours each in X, Y, and Z directions										
Shock resistance Destruction: 500			ction: 500 m/s ² (50G), three times each in X, Y, and Z directions							
Degree of protection		IEC60529 IP60								
Connection method (standard length) Pre-wired: 2 m										
Casing mate	erial	PBT (polybu	ıtylene terepht	halate)						
Cable material PVC (polyvinyl chloride resin)										

- Note: 1. The operation indicator of models with suffix code (A) or (R) will turn ON when the light is interrupted.
 - 2. The response frequency is a value obtained when the EE-SX detects a rotating disc with holes in it, as shown to the right.
 - Operates when the load current exceeds the rated value of 100 mA to inhibit a current flow exceeding 120 mA.

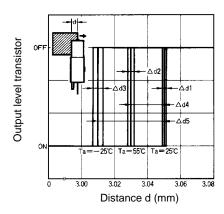


■ SENSING POSITION (EE-SX77/87)





■ REPEATED SENSING POSITION CHARACTERISTICS (TYPICAL)



No. of repetitions: 20 at $V_{\rm cc}$ = 12 V

 $\Delta d1 = 0.002 \text{ mm}$

 $\Delta d2 = 0.004 \text{ mm}$

 $\Delta d3 = 0.005 \text{ mm}$

 $\Delta d4 = 0.02 \text{ mm}$

 $\Delta d5 = 0.04 \text{ mm}$

Operation _____

■ OUTPUT CIRCUITS

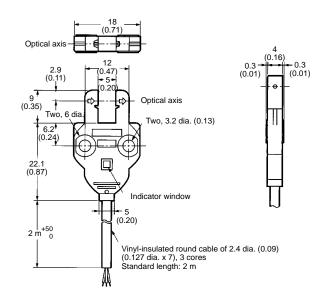
Output configuration	Model	Output transistor operation	Timing Charts		Output Circuit
NPN Output	EE-SX770 EE-SX771 EE-SX772 EE-SX770A EE-SX771A EE-SX772A	Dark-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF Operate Reset	Operation Load (e.g., relay) Black 5 to 24 VDC
	EE-SX870 EE-SX871 EE-SX872 EE-SX870A EE-SX871A EE-SX872A	Light-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF OPERATE Operate Reset	(Red) Main circuit 100 mA max.
PNP Output	EE-SX770P EE-SX771P EE-SX772P EE-SX770R EE-SX771R EE-SX772R	Dark-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF Operate Reset	Operation indicator Control output Black 50 mA max.
	EE-SX870P EE-SX871P EE-SX872P EE-SX870R EE-SX871R EE-SX872R	Light-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF Operate Reset	(Red) circuit 5 to 24 VDC Load (e.g., relay)

Unit: mm (inch)

STANDARD MODELS

EE-SX770 EE-SX870 EE-SX770A EE-SX870A EE-SX770P EE-SX870P EE-SX770R EE-SX870R

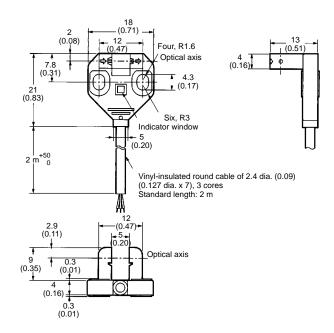




■ L-SHAPED MODELS

EE-SX771 EE-SX871 EE-SX771A EE-SX871A EE-SX771P EE-SX871P EE-SX771R EE-SX871R

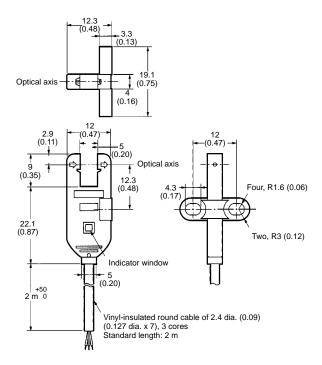




■ T-SHAPED MODELS

EE-SX772 EE-SX872 EE-SX772A EE-SX872A EE-SX772P EE-SX872P EE-SX772R EE-SX872R





Precautions

MOUNTING

- The EE-SX77/87 is a photomicrosensor that should be built into equipment. For this reason, no special protective measures have been taken to protect the EE-SX77/87 from external light disturbance. Avoid malfunction by ensuring that the EE-SX77/87 is not influenced by incandescent lamps or other light sources that may cause external light distur-
- Mount the photomicrosensor securely to flat plates. The characteristics of the through-beam sensor change if the slot is deformed.
- Use M3 screws when mounting the EE-SX77/87. Be sure to use spring washers with the screws, so that the screws will not loosen. The tightening torque applied to each screw must be no more than 0.59 N • m (6 kgf • cm).
- Make sure that nothing will come into contact with the sensing element of the sensor. If the sensing element has scratch damage, the operating characteristics of the photomicrosensor will decrease.
- Securely mount the EE-SX77/87 to prevent loosening by vibration or shock.

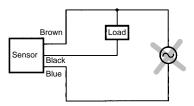
OPERATING ENVIRONMENT

- Do not connect the EE-SX77/87 while power is applied, or the EE-SX77/87 may be damaged.
- Do not install the EE-SX77/87 in the following locations to avoid malfunction or damage:
 - A. Locations with excessive dust
 - B. Locations with corrosive gas
 - C. Locations where water, oil, or chemicals are directly
 - D. Locations exposed to direct sunlight
- Make sure that the operating ambient temperature is within the rated range.
- The photomicrosensor may be soluble in organic solvent. acid, and alkaline, aromatic hydrocarbon, and chlorinated aliphatic hydrocarbon solvents. The characteristics of the photomicrosensor may decrease as a result. Make sure that the photomicrosensor is free from these solutions.

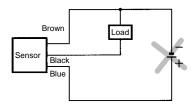
riangle!\ Caution

TO AVOID DAMAGE

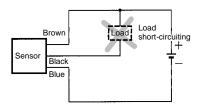
Do not use the EE-SX77/87 at voltage exceeding the rated voltage range.



Do not make mistakes in wiring, such as mistakes in polarity.



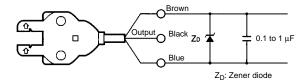
Do not short-circuit the load (i.e., do not connect a power supply directly to the Sensor) as shown below.



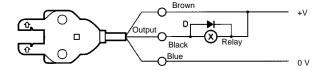
■ WIRING

For Surge Prevention

If the power supply has surge voltage, connect a Zener diode with standing 30 to 35 V or a 0.1 to 1- μ F capacitor in parallel to the power supply to absorb the surge voltage.



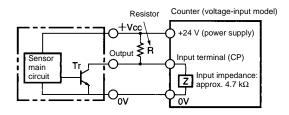
If the load is a relay or other small inductive load, connect it to the EE-SX77/87 as shown below. You must connect a diode for counter-voltage absorption.



Do not route power lines or high-tension lines in the same conduit with the EE-SX77/87 to avoid damage or malfunction due to induction.

Voltage Output

A photomicrosensor with open collector output can be connected to a device with voltage-input specifications by connecting a resistor between the power supply and output terminals, as shown in the following circuit diagram. The value of the resistor is normally 4.7 k Ω and must withstand a power of 0.5 W at 24 V and 0.25 W at 12 V.



• EE-SX77/87 series NPN models with a 4.7-k Ω resistor.

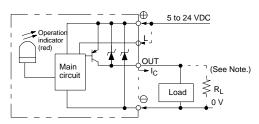
High level:

Input voltage (V_H) =
$$\frac{Z}{R+Z}$$
 V_{CC} = $\frac{4.7 \text{ k}}{4.7 \text{ k} + 4.7 \text{ k}}$ x 24 V = 12 V

Low level:

Input voltage $(V_I) \le 0.4 \text{ V}$

Load current (I_C) =
$$\frac{V_{CC}}{R}$$
 = $\frac{24 \text{ V}}{R}$ = 5.1 mA \leq 100 mA



Note: When using a voltage output, always insert a resistor in R_I.

Note: Refer to the ratings of the photomicrosensor for the relationship between the residual voltage and load current.

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